

April 1995

8-Bit 250 MSPS Flash A/D Converter

Features

- Differential Linearity Error ± 0.5 LSB or Less
- Integral Linearity Error ± 0.5 LSB or Less
- Built-In Integral Linearity Compensation Circuit
- Ultra High Speed Operation with Maximum Conversion Rate of 250 MSPS (Min)
- Low Input Capacitance 18pF (Typ)
- Wide Analog Input Bandwidth 200MHz (Min. for Full-Scale Input)
- Single Power Supply -5.2V
- Low Power Consumption 1400mW (Typ)
- Low Error Rate
- Capable of Driving 50Ω Loads

Applications

- Spectrum Analyzers
- Radar Systems
- Direct RF Down-Conversion
- Video Digitizing
- Communication Systems
- Digital Oscilloscopes

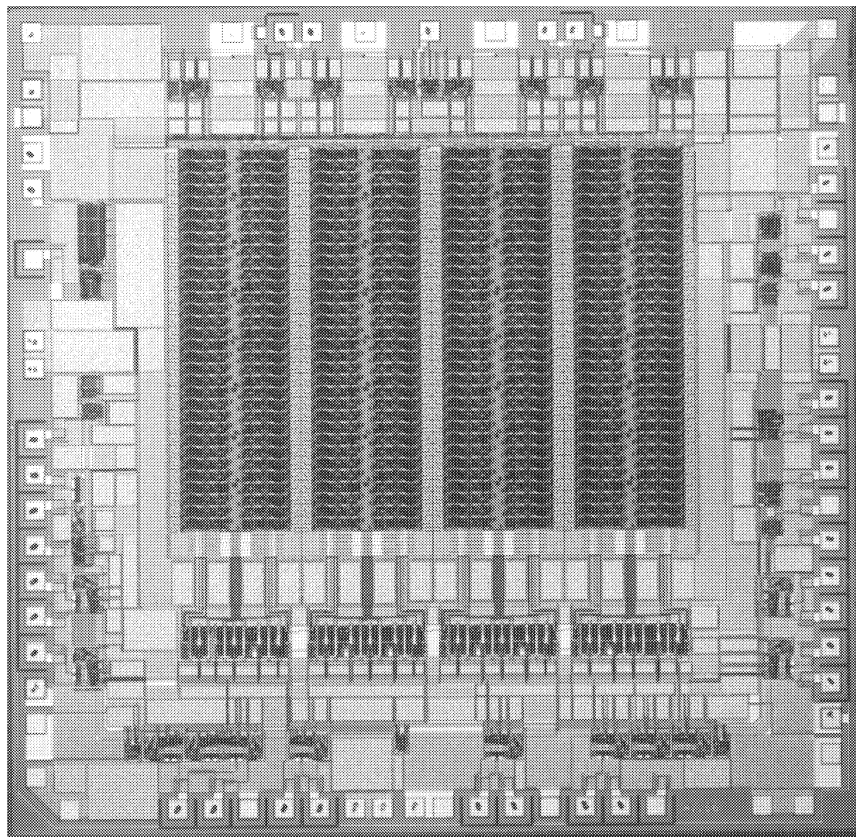
Description

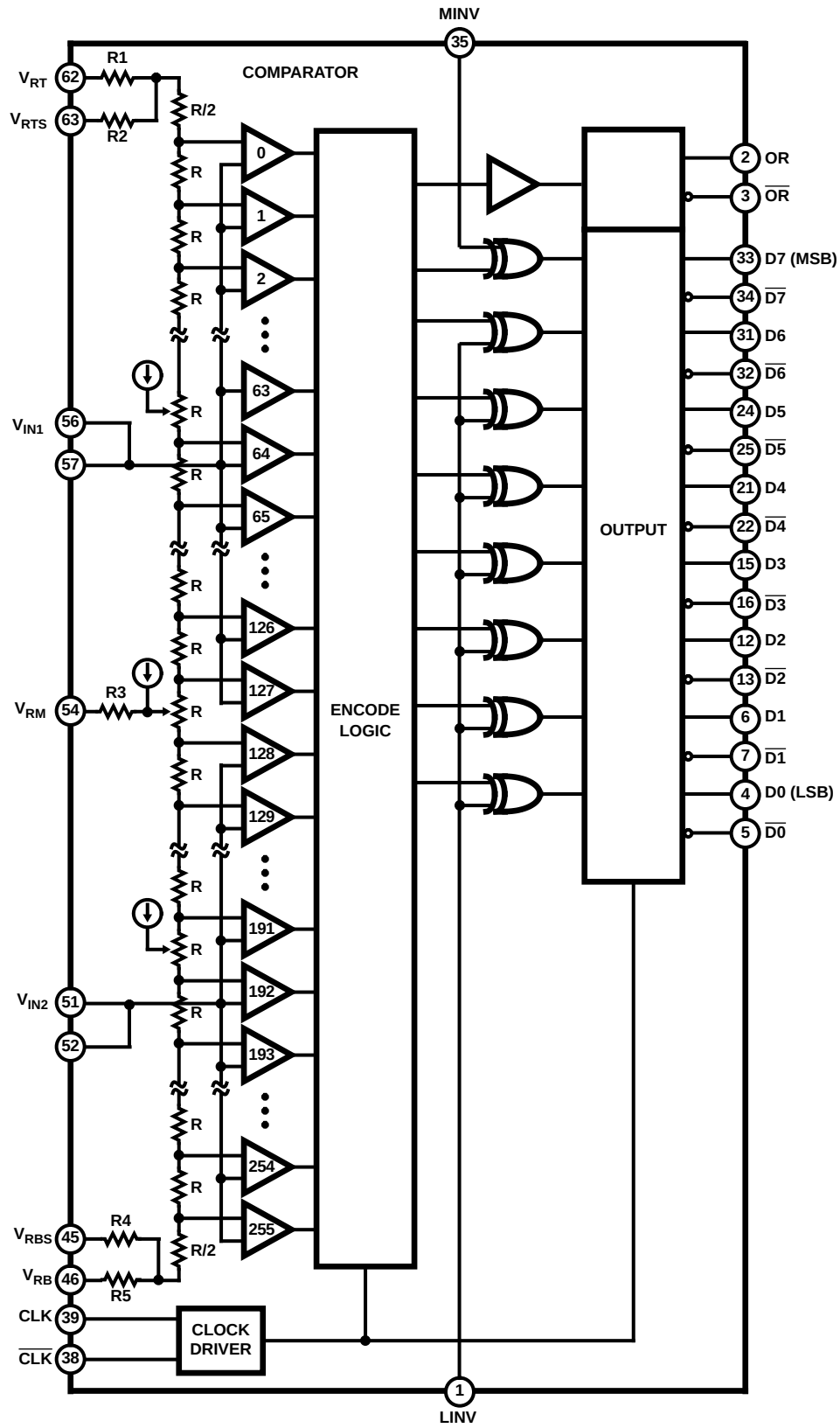
This is a specification that outlines the mechanical and electrical characteristics for the HI1166Y, 8-bit Flash A/D converter IC, in chip (die) form.

Ordering Information

PART NUMBER	TEMPERATURE	PACKAGE
HI1166Y	+25°C	Die
• All performance parameters are for packaged devices when supplied by Harris.		

Die Metallization Layer



Functional Block Diagram

Specifications HI1166Y

Absolute Maximum Ratings $T_A = +25^{\circ}\text{C}$

Supply Voltage (AV_{EE} , DV_{EE})	-7V to +0.5V	V_{RM} Pin Input Current (I_{VRM})	-3mA to +3mA
Analog Input Voltage (V_{IN})	-2.7V to +0.5V	Digital Output Current	
Reference Input Voltage		($ID0$ to $ID7$, IOR , $ID0$ to $ID7$, IOR)	-30mA to 0mA
V_{RT} , V_{RB} , V_{RM}	-2.7V to +0.5V	Storage Temperature Range (T_{STG})	-65°C to +150°C
$ V_{RT} - V_{RB} $	2.5V		
Digital Input Voltage			
$\overline{MINV}$, $\overline{LINV}$, CLK , $\overline{CLK}$	-4V to +0.5V		
$ CLK - \overline{CLK} $	2.7V		

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Operating Conditions

Supply Voltage		Reference Input Voltage	
AV_{EE} , DV_{EE}	-5.5V to -4.95V	V_{RT}	-0.1V to 0.1V
AV_{EE} - DV_{EE}	-0.05V to 0.05V	V_{RB}	-2.2V to -1.8V
AGND - DGND	-0.05V to 0.05V	Analog Input Voltage, V_{IN}	V_{RB} to V_{RT}

Electrical Specifications $T_A = +25^{\circ}\text{C}$, DV_{EE} , $AV_{EE} = -5.2\text{V}$, $V_{RT} = 0\text{V}$, $V_{RB} = -2\text{V}$

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Differential Linearity Error (DNL) (00000000 to 11111111)		-0.7	0.7	LSB
Integral Linearity Error (INL) (00000000 to 11111111)		-0.7	0.7	LSB
Resolution		8	-	Bits
Input Bias Current, I_{IN}	$V_{IN} = -1.0\text{V}$	35	400	μA
Analog Input Resistance, R_{IN}	$V_{IN} = -1.0\text{V}$	55	350	$\text{k}\Omega$
Resister-String Current, I_{REF}		-24	-13	mA
Reference Voltage, V_{RM}		-1.1	-0.9	V
Residual Resistance, R1		0.1	1.2	Ω
Residual Resistance, R2		380	620	Ω
Residual Resistance, R5		0.1	1.2	Ω
Residual Resistance, R4		380	620	Ω
Digital Input Current HI, I_{IH}	$H_i = -0.8\text{V}$	0	40	μA
Digital Input Current LO, I_{IL}	$L_o = -1.6\text{V}$	-30	30	μA
$\overline{CLK}$ Open Voltage, V_{OPN}	$\overline{CLK} = \text{Open}$	-1.4	-1.2	V
Leakage (1) D0 to D7, V_{LEAK}	$I = -10\mu\text{A}$	-1.0	-0.3	V
Leakage (2) D0 to D7, V_{IN} , $\overline{LINV}$, $\overline{MINV}$, CLK , $\overline{CLK}$, I_{LEAK}	$V = 0.3\text{V}$	-1.0	1.0	μA
Digital Output Voltage HI, V_{OH}	620 Ω to -5.2V	-1	-0.6	V
Digital Output Voltage LO, V_{OL}	620 Ω to -5.2V	-2	-1.55	V
Supply Current, I_{EE}		-330	-190	mA

Timing Diagram

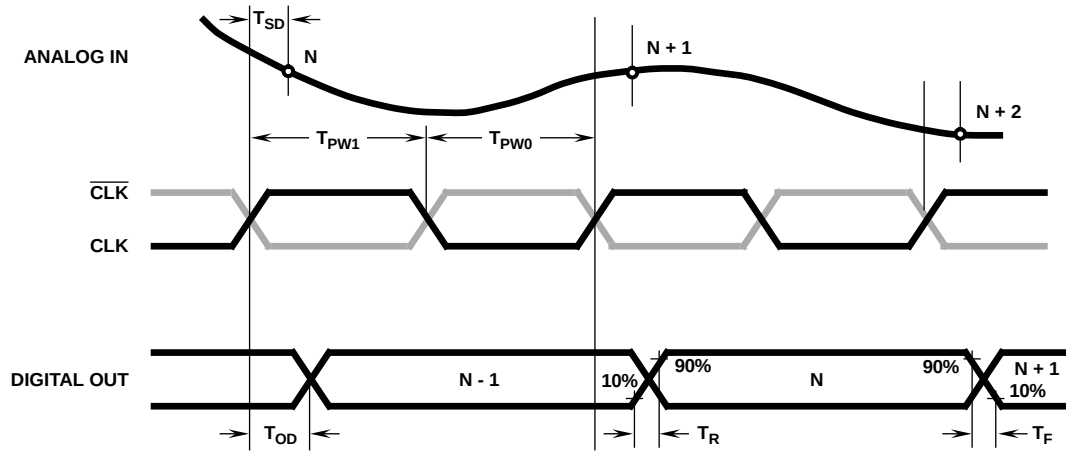


FIGURE 1.

Pad Descriptions

PAD NUMBER	SYMBOL	I/O	STANDARD VOLTAGE LEVEL	EQUIVALENT CIRCUIT	DESCRIPTION
4, 5	D0, $\overline{D0}$	O	ECL		LSB and complementary LSB output.
6, 7	D1, $\overline{D1}$				D1 to D6: Data output D1 to D6: Complementary Data output
12, 13	D2, $\overline{D2}$				
14, 15	D3, $\overline{D3}$				
21, 22	D4, $\overline{D4}$				
24, 25	D5, $\overline{D5}$				
31, 32	D6, $\overline{D6}$				
33, 34	D7, $\overline{D7}$				MSB complementary MSB data output.
2, 3	OR, $\overline{OR}$	I	ECL		Overrange and complementary overrange output.
1	LINV				Polarity selection for LSBs (refer to the A/D Output Code Table.) Pulled low when left open.
35	MINV	I	ECL		Polarity selection for MSBs (refer to the A/D Output Code Table.) Pulled low when left open.

Pad Descriptions (Continued)

PAD NUMBER	SYMBOL	I/O	STANDARD VOLTAGE LEVEL	EQUIVALENT CIRCUIT	DESCRIPTION
39	CLK	I	ECL		CLK Input
38	CLK				Complementary CLK input. Pulled down to -1.3V when left open.
62	V_{RT}	I	0V		Analog reference voltage (top) (0V Typ.).
63	V_{RTS}	O	0V		Reference voltage sense (top).
54	V_{RM}	I	$V_{RB}/2$		Reference voltage mid point. Can be used for linearity compensation.
45	V_{RBS}	O	-2V		Reference voltage sense (bottom).
46	V_{RB}	I	-2V		Analog reference voltage (bottom).
51, 52	V_{IN2}	I	V_{RTS} to V_{RBS}		Analog input. All of the pins must be wired externally.
56, 57	V_{IN1}				

Pad Descriptions (Continued)

PAD NUMBER	SYMBOL	I/O	STANDARD VOLTAGE LEVEL	EQUIVALENT CIRCUIT	DESCRIPTION
49, 50, 53, 55, 58, 59	AGND	-	0V		Analog ground.
40, 41, 47, 48, 60, 61, 65, 66	AV _{EE}		-5.2V		Analog supply. Internally connected to DV _{EE} (resistance: 4Ω to 6Ω).
9, 19, 20, 29	DGND1		0V		Digital ground.
10, 17, 18, 27, 28	DGND2		0V		Digital ground for output drive.
8, 14, 23, 30	DV _{EE}		-5.2V		Digital supply. Internally connected to AV _{EE} (resistance: 4Ω to 6Ω).

A/D OUTPUT CODE TABLE

V _{IN} (Note 1)	STEP	MINV 1 LINV 1			0 1			1 0			0 0		
		OR	D7	D0	OR	D7	D0	OR	D7	D0	OR	D0	D7
0V	0	0	000	00	0	100	00	0	011	11	0	111	11
		1	000	00	1	100	00	1	011	11	1	111	11
		1	000	01	1	100	01	1	011	10	1	111	10
-1V	127		.			.			.			.	
			.			.			.			.	
			.			.			.			.	
	128	1	011	11	1	111	11	1	000	00	1	100	00
		1	100	00	1	000	00	1	111	11	1	011	11
			.			.			.			.	
-2V	254	1	111	10	1	011	10	1	100	01	1	000	01
	255	1	111	11	1	011	11	1	100	00	1	000	00
	1		.			.			.			.	
		1	111	11	1	011	11	1	100	00	1	000	00

NOTE:

1. V_{RT} = V_{RTS} = 0V, V_{RM} = -1V or open, V_{RB} = V_{RBS} = -2V

Pad Coordinates**PAD COORDINATE 1**

PAD NO.	PAD NAME	X [μm]	Y [μm]
1	LINV	2198.40	4490.40
2	OR	2008.00	4490.40
3	$\overline{\text{OR}}$	1817.60	4490.40
4	D0	1627.20	4490.40
5	$\overline{\text{D0}}$	1436.80	4490.40
6	D1	1246.40	4490.40
7	$\overline{\text{D1}}$	1056.00	4490.40
8	DV _{EE}	865.60	4490.40
9	DGND1	675.20	4490.40
10	DGND2	388.80	4490.40
11	DGND2	209.60	4311.20
12	D2	209.60	3730.40
13	$\overline{\text{D2}}$	209.60	3540.00
14	DV _{EE}	209.60	3349.60
15	D3	209.60	3159.20
16	$\overline{\text{D3}}$	209.60	2968.80
17	DGND2	209.60	2778.40
18	DGND2	209.60	2629.60
19	DGND1	209.60	2458.40
20	DGND1	209.60	2301.60
21	D4	209.60	2111.20
22	$\overline{\text{D4}}$	209.60	1920.80

PAD NO.	PAD NAME	X [μm]	Y [μm]
23	DV _{EE}	209.60	1730.40
24	D5	209.60	1540.00
25	$\overline{\text{D5}}$	209.60	1349.60
26		209.60	1159.20
27	DGND2	209.60	588.00
28	DGND2	209.60	362.40
29	DGND1	484.80	215.20
30	DV _{EE}	675.20	215.20
31	D6	865.60	215.20
32	$\overline{\text{D6}}$	1056.00	215.20
33	D7	1246.40	215.20
34	$\overline{\text{D7}}$	1436.80	215.20
35	MINV	1627.20	215.20
36		1817.60	215.20
37		2008.00	215.20
38	$\overline{\text{CLK}}$	2198.40	215.20
39	CLK	2388.80	215.20
40	AV _{EE}	2579.20	215.20
41	AV _{EE}	2728.00	215.20
42		2974.40	215.20
43		3164.80	215.20
44		3355.20	215.20

PAD NO.	PAD NAME	X [μm]	Y [μm]
45	V _{RBS}	3545.60	215.20
46	V _{RB}	3736.00	215.20
47	AV _{EE}	3926.40	215.20
48	AV _{EE}	4075.20	215.20
49	AGND	4377.60	215.20
50	AGND	4377.60	1292.00
51	V _{IN2}	4377.60	1570.40
52	V _{IN2}	4377.60	1720.80
53	AGND	4377.60	1999.20
54	V _{RM}	4377.60	2352.80
55	AGND	4377.60	2698.40
56	V _{IN1}	4377.60	2984.80
57	V _{IN1}	4377.60	3135.20
58	AGND	4377.60	3413.60
59	AGND	4377.60	4490.40
60	AV _{EE}	4075.20	4490.40
61	AV _{EE}	3926.40	4490.40
62	V _{RT}	3736.00	4490.40
63	V _{RTS}	3545.60	4490.40
64		3164.80	4490.40
65	AV _{EE}	2728.00	4490.40
66	AV _{EE}	2579.20	4490.40

Pad Coordinates (Continued)**PAD COORDINATE 2**

PAD NO.	PAD NAME	X [μ m]	Y [μ m]
1	LINV	2158.40	4450.40
2	OR	1968.00	4450.40
3	$\overline{\text{OR}}$	1777.60	4450.40
4	D0	1587.20	4450.40
5	$\overline{\text{D0}}$	1396.80	4450.40
6	D1	1206.40	4450.40
7	$\overline{\text{D1}}$	1016.00	4450.40
8	DV _{EE}	825.60	4450.40
9	DGND1	635.20	4450.40
10	DGND2	348.80	4450.40
11	DGND2	169.60	5271.20
12	D2	169.60	3690.40
13	$\overline{\text{D2}}$	169.60	3500.00
14	DV _{EE}	169.60	3309.60
15	D3	169.60	3119.20
16	$\overline{\text{D3}}$	169.60	2928.80
17	DGND2	169.60	2738.40
18	DGND2	169.60	2589.60
19	DGND1	169.60	2418.40
20	DGND1	169.60	2261.60
21	D4	169.60	2071.20
22	$\overline{\text{D4}}$	169.60	1880.80

PAD NO.	PAD NAME	X [μ m]	Y [μ m]
23	DV _{EE}	169.60	1690.40
24	D5	169.60	1500.00
25	$\overline{\text{D5}}$	169.60	1309.60
26		169.60	1119.20
27	DGND2	169.60	548.00
28	DGND2	169.60	322.40
29	DGND1	444.80	175.20
30	DV _{EE}	635.20	175.20
31	D6	825.60	175.20
32	$\overline{\text{D6}}$	1016.00	175.20
33	D7	1206.40	175.20
34	$\overline{\text{D7}}$	1396.80	175.20
35	MINV	1587.20	175.20
36		1777.60	175.20
37		1968.00	175.20
38	$\overline{\text{CLK}}$	2158.40	175.20
39	CLK	2348.80	175.20
40	AV _{EE}	2539.20	175.20
41	AV _{EE}	2688.00	175.20
42		2934.40	175.20
43		3124.80	175.20
44		3315.20	175.20

PAD NO.	PAD NAME	X [μ m]	Y [μ m]
45	V _{RBS}	3505.60	175.20
46	V _{RB}	3696.00	175.20
47	AV _{EE}	3886.40	175.20
48	AV _{EE}	4035.20	175.20
49	AGND	4337.60	175.20
50	AGND	4337.60	1252.00
51	V _{IN2}	4337.60	1530.40
52	V _{IN2}	4337.60	1680.80
53	AGND	4337.60	1959.20
54	V _{RM}	4337.60	2312.80
55	AGND	4337.60	2658.40
56	V _{IN1}	4337.60	2944.80
57	V _{IN1}	4337.60	3095.20
58	AGND	4337.60	3373.60
59	AGND	4337.60	4450.40
60	AV _{EE}	4035.20	4450.40
61	AV _{EE}	3886.40	4450.40
62	V _{RT}	3696.00	4450.40
63	V _{RTS}	3505.60	4450.40
64		3124.80	4450.40
65	AV _{EE}	2688.00	4450.40
66	AV _{EE}	2539.20	4450.40

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